

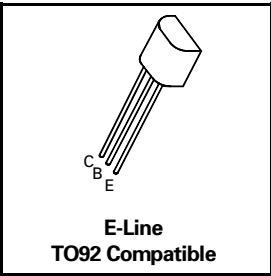
NPN SILICON PLANAR MEDIUM POWER DARLINGTON TRANSISTORS

ZTX600
ZTX601

ISSUE 2 – JUNE 94

FEATURES

- * 160 Volt V_{CEO}
- * 1 Amp continuous current
- * Gain of 5K at $I_C=1$ Amp
- * $P_{tot} = 1$ Watt



ABSOLUTE MAXIMUM RATINGS.

| PARAMETER | SYMBOL | ZTX600 | ZTX601 | UNIT |
|--|----------------|-------------|--------|------------|
| Collector-Base Voltage | V_{CBO} | 160 | 180 | V |
| Collector-Emitter Voltage | V_{CEO} | 140 | 160 | V |
| Emitter-Base Voltage | V_{EBO} | 10 | | V |
| Peak Pulse Current | I_{CM} | 4 | | A |
| Continuous Collector Current | I_C | 1 | | A |
| Power Dissipation at $T_{amb}=25^{\circ}C$ derate above $25^{\circ}C$ | P_{tot} | 1 5.7 | | W mW/°C |
| Operating and Storage Temperature Range | $T_j; T_{stg}$ | -55 to +200 | | °C |

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ unless otherwise stated).

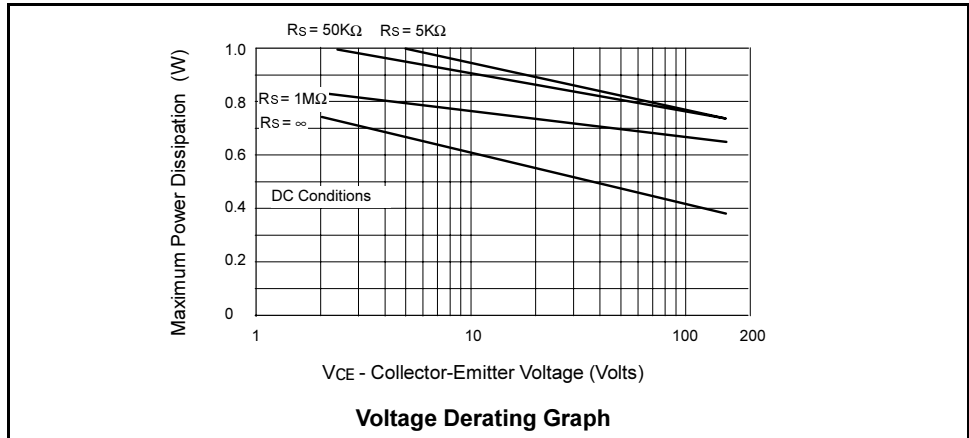
| PARAMETER | SYMBOL | ZTX600 | | | ZTX601 | | | UNIT | CONDITIONS. |
|--------------------------------------|---------------|--------|--------------|------------|--------|--------------|------------|--|--|
| | | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. | | |
| Collector-Base Breakdown Voltage | $V_{(BR)CBO}$ | 160 | | | 180 | | | V | $I_C=100\mu A$ |
| Collector-Emitter Breakdown Voltage | $V_{(BR)CEO}$ | 140 | | | 160 | | | V | $I_C=10mA^*$ |
| Emitter-Base Breakdown Voltage | $V_{(BR)EBO}$ | 10 | | | 10 | | | V | $I_E=100\mu A$ |
| Collector Cut-Off Current | I_{CBO} | | | 0.01 10 | | | 0.01 10 | μA μA μA μA | $V_{CB}=140V$ $V_{CB}=160V$ $V_{CB}=140V, T_a=100^{\circ}C$ $V_{CB}=160V, T_a=100^{\circ}C$ |
| Emitter Cut-Off Current | I_{EBO} | | | 0.1 | | | 0.1 | μA | $V_{EB}=8V$ |
| Collector-Emitter Cut-Off Current | I_{CES} | | | 10 | | | 10 | μA μA | $V_{CES}=140V$ $V_{CES}=160V$ |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | | 0.75 0.85 | 1.1 1.2 | | 0.75 0.85 | 1.1 1.2 | V V | $I_C=0.5A, I_B=5mA^*$ $I_C=1A, I_B=10mA^*$ |
| Base-Emitter Saturation Voltage | $V_{BE(sat)}$ | | 1.7 | 1.9 | | 1.7 | 1.9 | V | $I_C=1A, I_B=10mA^*$ |
| Base-Emitter Turn-On Voltage | $V_{BE(on)}$ | | 1.5 | 1.7 | | 1.5 | 1.7 | V | $I_C=1A, V_{CE}=5V^*$ |

ZTX600 ZTX601

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated).

| PARAMETER | SYMBOL | ZTX600 | | | ZTX601 | | | UNIT | CONDITIONS. |
|---------------------------------------|-----------|-----------------|-------------------|------|-----------------|-------------------|------|---------------|--|
| | | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. | | |
| Static Forward Current Transfer Ratio | h_{FE} | 1K 2K 1K | | 100K | 1K 2K 1K | | 100K | | $I_C=50\text{mA}, V_{CE}=10\text{V}^*$ $I_C=0.5\text{A}, V_{CE}=10\text{V}^*$ $I_C=1\text{A}, V_{CE}=10\text{V}^*$ |
| Group A | | 1K 2K 1K | 2K 5K 3K | 20K | 1K 2K 1K | 2K 5K 3K | 20K | | $I_C=50\text{mA}, V_{CE}=10\text{V}^*$ $I_C=0.5\text{A}, V_{CE}=10\text{V}^*$ $I_C=1\text{A}, V_{CE}=10\text{V}^*$ |
| Group B | | 5K 10K 5K | 10K 20K 10K | 100K | 5K 10K 5K | 10K 20K 10K | 100K | | $I_C=50\text{mA}, V_{CE}=10\text{V}^*$ $I_C=0.5\text{A}, V_{CE}=10\text{V}^*$ $I_C=1\text{A}, V_{CE}=10\text{V}^*$ |
| Transition Frequency | f_T | 150 | 250 | | 150 | 250 | | MHz | $I_C=100\text{mA}, V_{CE}=10\text{V}, f=20\text{MHz}$ |
| Input Capacitance | C_{ibo} | | 60 | 90 | | 60 | 90 | pF | $V_{EB}=0.5\text{V}, f=1\text{MHz}$ |
| Output Capacitance | C_{obo} | | 10 | 15 | | 10 | 15 | pF | $V_{CE}=10\text{V}, f=1\text{MHz}$ |
| Switching Times | t_{on} | | 0.75 | | | 0.75 | | μs | $I_C=0.5\text{A}, V_{CE}=10\text{V}$ $I_{B1}=I_{B2}=0.5\text{mA}$ |
| | t_{off} | | 2.2 | | | 2.2 | | μs | |

*Measured under pulsed conditions. Pulse width=300 μs . Duty cycle $\leq 2\%$



The maximum permissible operational temperature can be obtained from this graph using the following equation

$$T_{amb(max)} = \frac{\text{Power(max)} - \text{Power(act)}}{0.0057} + 25^{\circ}\text{C}$$

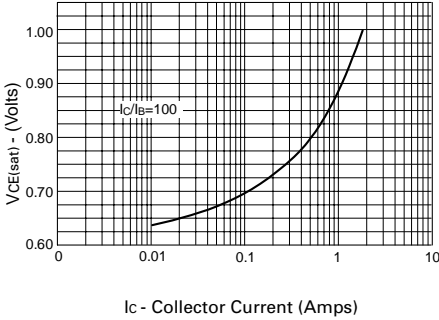
$T_{amb(max)}$ = Maximum operating ambient temperature

Power(max) = Maximum power dissipation figure, obtained from the above graph for a given V_{CE} and source resistance (R_s)

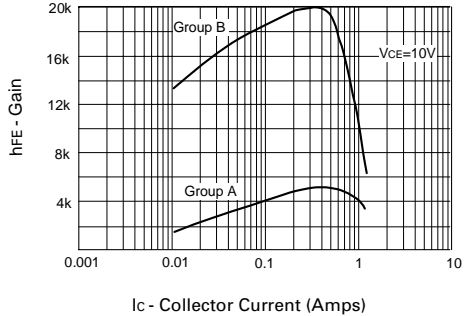
Power(actual) = Actual power dissipation in users circuit

ZTX600 ZTX601

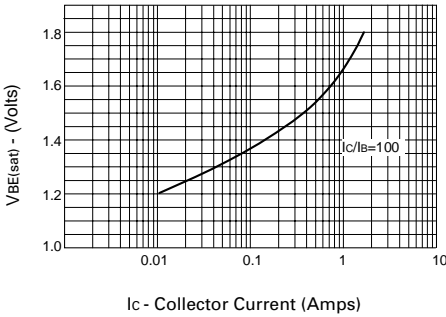
TYPICAL CHARACTERISTICS



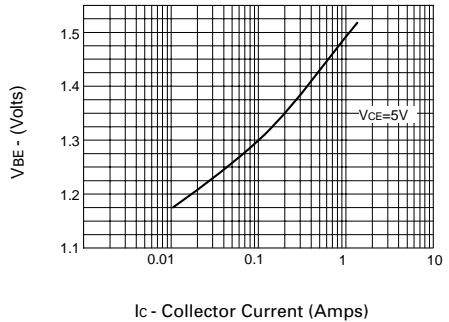
$V_{CE(sat)}$ v I_C



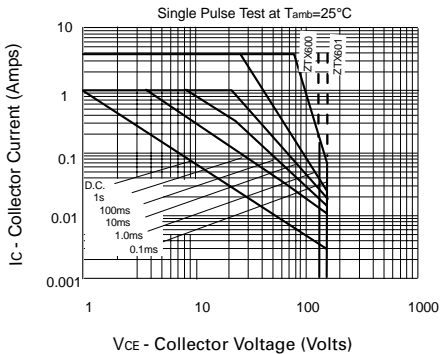
hFE v I_C



$V_{BE(sat)}$ v I_C



$V_{BE(on)}$ v I_C



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